

Supporting Information

Improved thermoelectric performance of copper-deficient compounds $\text{Cu}_{2.5+\delta}\text{In}_{4.5}\text{Te}_8$ ($\delta=0-0.15$) with an excess of Cu caused by formation of impurity bands and reduction in lattice thermal conductivity

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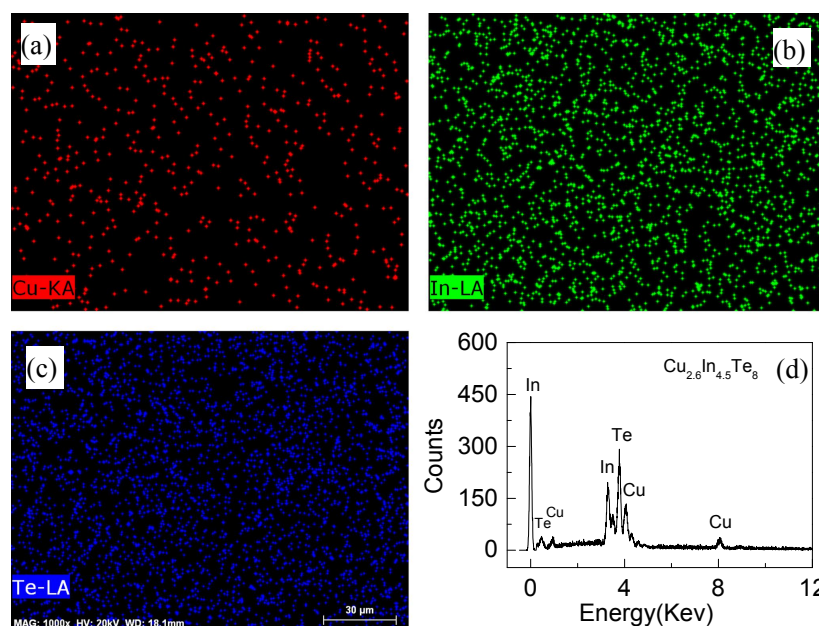


Fig. S1 EPMA mappings of three elements on polished $\text{Cu}_{2.6}\text{In}_{4.5}\text{Te}_8$ surface (a) Cu, (b) In, (c) Te, (d) an EDAX pattern.

Table S1 Average chemical compositions (relative molar) identified in $\text{Cu}_{2.5}\text{In}_{4.5}\text{Te}_8$ and $\text{Cu}_{2.6}\text{In}_{4.5}\text{Te}_8$ (taken from different mappings)

Compounds	Cu	In	Te
$\text{Cu}_{2.5}\text{In}_{4.5}\text{Te}_8$	2.53	4.51	8.0
$\text{Cu}_{2.6}\text{In}_{4.5}\text{Te}_8$	2.62	4.53	8.0

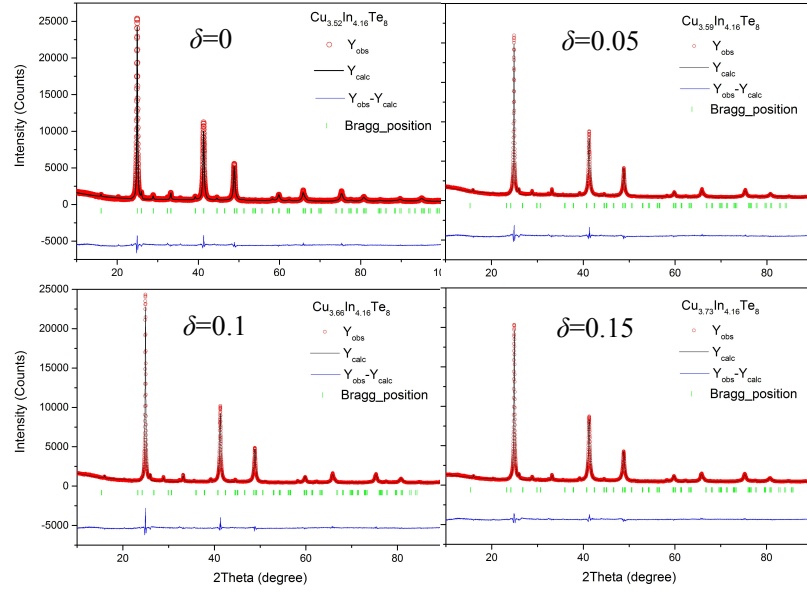


Fig. S2 Rietveld refinements using X-ray diffraction data of four compounds $\text{Cu}_{2.5+\delta}\text{In}_{4.5}\text{Te}_8$ ($\delta=0, 0.05, 0.1, 0.15$).

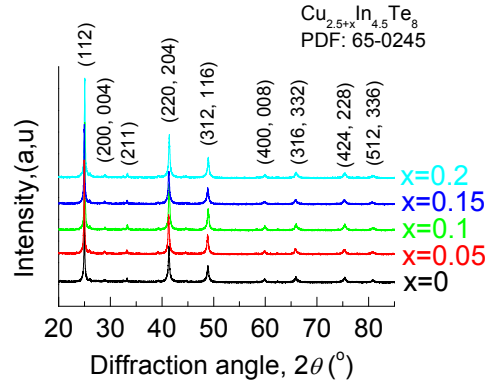


Fig. S3 XRD patterns of the powders of $\text{Cu}_{2.5+\delta}\text{In}_{4.5}\text{Te}_8$ ($\delta=0, 0.05, 0.1, 0.15, 0.2$).

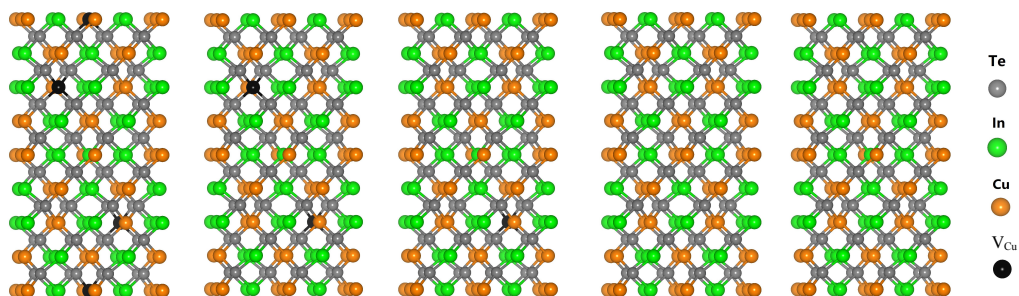


Fig. S4 Crystal structures of $\text{Cu}_{28+y}\text{In}_{33}\text{Te}_{64}$ ($y=0-4$) assuming that added Cu atoms reside in the Cu vacancy.

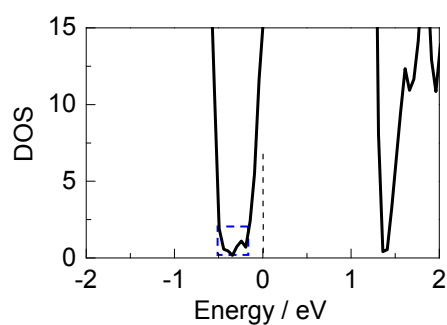


Fig. S5 Close-up view of the impurity band (IB) in the density of states (DOS) of $\text{Cu}_{28+y}\text{In}_{33}\text{Te}_{64}$ ($y=0-4$) system.

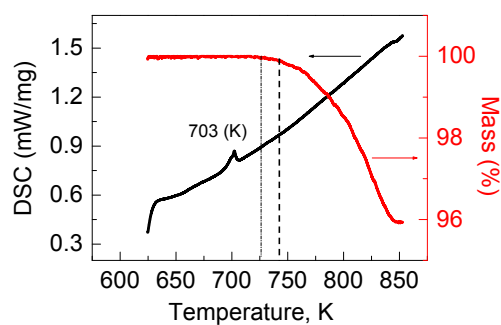


Fig. S6 Differential scanning calorimetry (DSC) and weight loss (TG) signals as a function of temperature for $\text{Cu}_{2.5}\text{In}_{4.5}\text{Te}_8$.